NSN 5961-01-371-0990

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-371-0990 **Inclosure Material:** Ceramic **Overall Length:** 0.150 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.200 inches **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, dc **Current Rating Per Characteristic:** 1.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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